



**Product data sheet** 

### 1. Product profile

#### 1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

#### 1.2 Features and benefits

- High speed switching for RF signals
- Low diode capacitance
- Low forward resistance
- Very low series inductance
- For applications up to 3 GHz

#### **1.3 Applications**

RF attenuators and switches

### 2. Pinning information

Table 1.	Discrete pinning		
Pin	Description	Simplified outline	Symbol
1	cathode	[1]	
2	anode		$\mathbf{A}$
		Transparent top view	sym006

[1] The marking bar indicates the cathode.

### 3. Ordering information

# Table 2. Ordering information Type number Package Name Description Version BAP55LX DFN1006D-2 leadless ultra small plastic package; 2 terminals; body 1 × 0.6 × 0.4 mm SOD882D

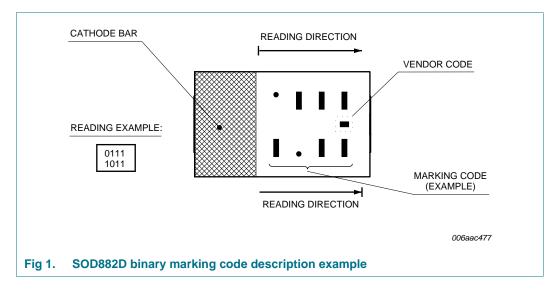


### 4. Marking

Table 3. Marking codes	
Type number	Marking code <sup>[1]</sup>
BAP55LX	1111 1101

[1] For SOD882D binary marking code description, see Figure 1.

#### 4.1 Binary marking code description



### 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

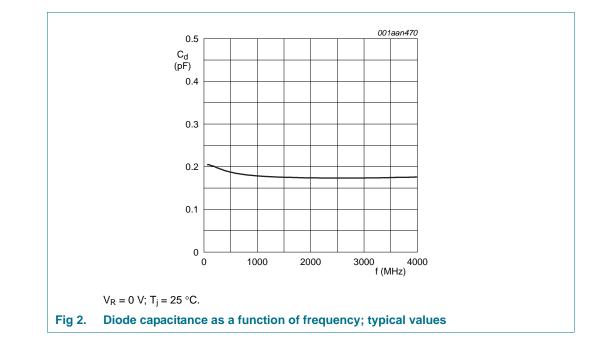
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>R</sub>	reverse voltage		-	50	V
l <sub>F</sub>	forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	135	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

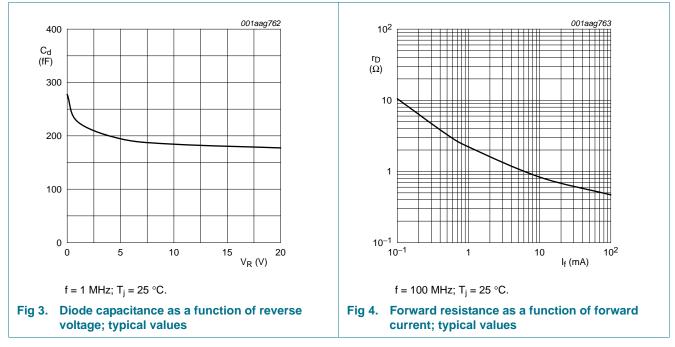
### 6. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		78	K/W

### 7. Characteristics

$T_{amb} = 25$	C unless otherwise specified	d				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VF	forward voltage	I <sub>F</sub> = 50 mA	-	0.95	1.1	V
R	reverse current	V <sub>R</sub> = 20 V	-	-	10	nA
		V <sub>R</sub> = 50 V	-	-	100	nA
Cd	diode capacitance	see <u>Figure 3;</u> f = 1 MHz;				
		$V_R = 0 V$	-	0.28	-	pF
		$V_R = 1 V$	-	0.23	-	pF
		V <sub>R</sub> = 20 V	-	0.18	0.28	pF
D	diode forward resistance	see <u>Figure 4;</u> f = 100 MHz;				
		I <sub>F</sub> = 0.5 mA	-	3.3	4.5	Ω
		I <sub>F</sub> = 1 mA	-	2.2	3.3	Ω
		I <sub>F</sub> = 10 mA	-	0.8	1.2	Ω
		I <sub>F</sub> = 100 mA	-	0.5	0.8	Ω
SL	isolation	see Figure 5; $V_R = 0 V$ ;				
		f = 900 MHz	-	19	-	dB
		f = 1800 MHz	-	14	-	dB
		f = 2450 MHz	-	12	-	dB
L <sub>ins</sub> ins	insertion loss	see <u>Figure 6;</u> I <sub>F</sub> = 0.5 mA;				
		f = 900 MHz	-	0.24	-	dB
		f = 1800 MHz	-	0.25	-	dB
		f = 2450 MHz	-	0.26	-	dB
L <sub>ins</sub>	insertion loss	see <u>Figure 6;</u> I <sub>F</sub> = 1 mA;				
		f = 900 MHz	-	0.17	-	dB
		f = 1800 MHz	-	0.18	-	dB
		f = 2450 MHz	-	0.19	-	dB
-ins	insertion loss	see <u>Figure 6;</u> I <sub>F</sub> = 10 mA;				
		f = 900 MHz	-	0.08	-	dB
		f = 1800 MHz	-	0.09	-	dB
		f = 2450 MHz	-	0.10	-	dB
-ins	insertion loss	see <u>Figure 6;</u> I <sub>F</sub> = 100 mA;				
-1115		f = 900 MHz	-	0.05	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.08	-	dB
Ľ	charge carrier life time	when switched from $I_F = 10$ mA to $I_R = 6$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 3$ mA	0.225	0.27	-	μS
-S	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	0.4	-	nH





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#### 001aag764 001aag765 0 0 (1) L<sub>ins</sub> (dB) ISL (dB) (3) (2) -0.2 -10 (4) -0.4 -20 -0.6 -30 -0.8 -40 -1.0 0 1000 2000 3000 0 1000 2000 3000 f (MHz) f (MHz) $T_{amb} = 25 \ ^{\circ}C$ T<sub>amb</sub> = 25 °C (1) $I_F = 100 \text{ mA}$ Diode zero biased and inserted in series with a 50 $\Omega$ stripline circuit (2) I<sub>F</sub> = 10 mA (3) I<sub>F</sub> = 1 mA (4) $I_F = 0.5 \text{ mA}$ Diode inserted in series with a 50 $\Omega$ stripline circuit and biased via the analyzer Tee network Fig 5. Isolation of the diode as a function of Fig 6. Insertion loss of the diode as a function of frequency; typical values frequency; typical values

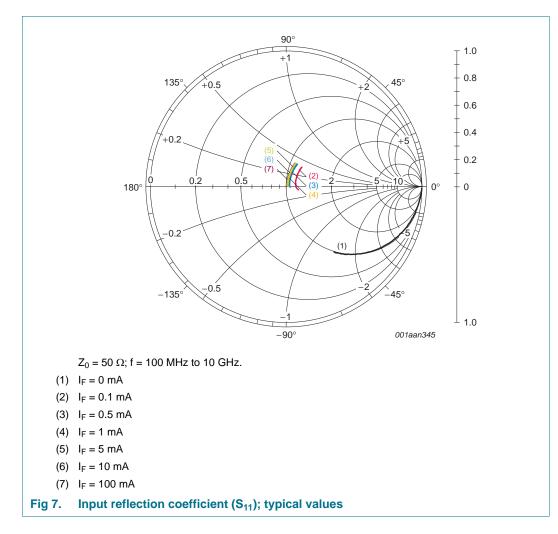
BAP55LX

**BAP55LX** 

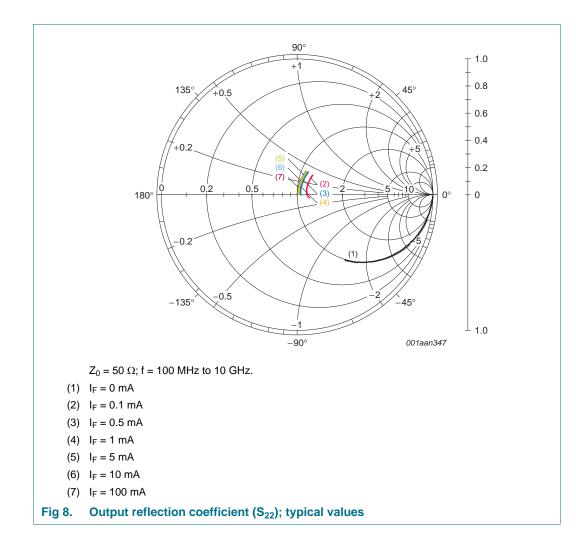
Silicon PIN diode

### 7.1 S-parameters

### 7.1.1 Diode in series configuration

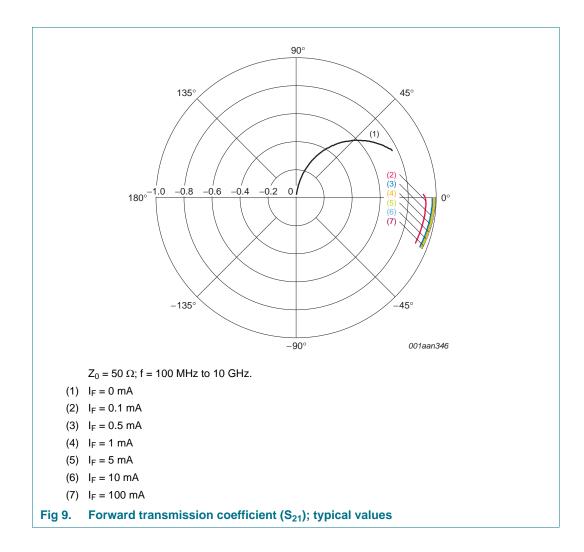


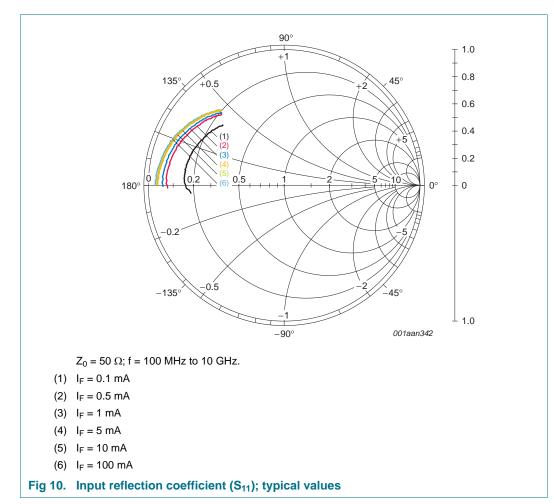




BAP55LX

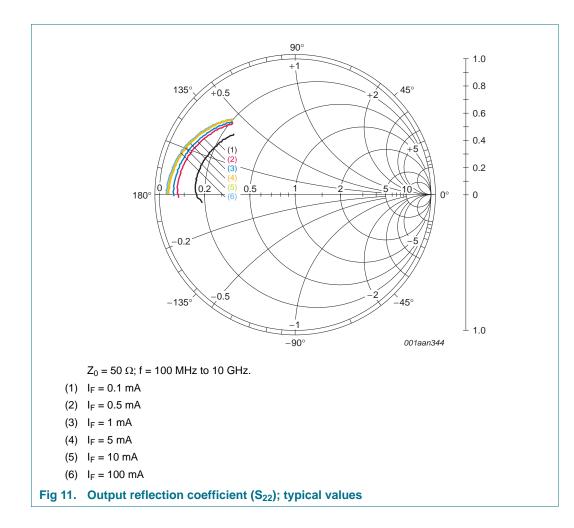
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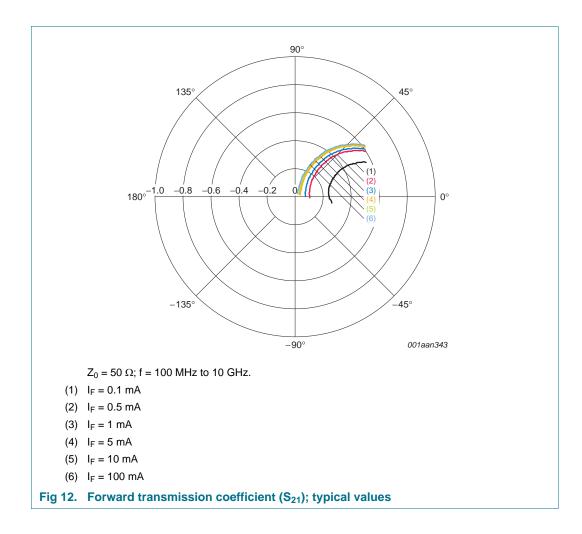




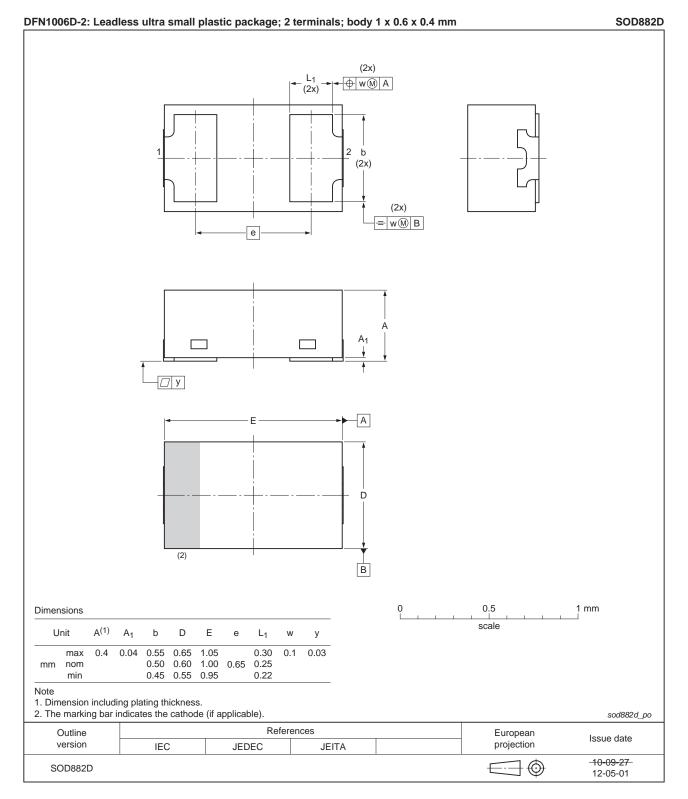
### 7.1.2 Diode in parallel configuration







### 8. Package outline



#### Fig 13. Package outline SOD882D (DFN1006D-2)

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### 9. Abbreviations

Table 7. Ab	breviations
Acronym	Description
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency

## **10. Revision history**

Table 8. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP55LX v.4	20130806	Product data sheet	-	BAP55LX v.3
Modifications:	<ul> <li>Table 1 on particular</li> <li>Table 2 on particular</li> <li>Section 4 on</li> </ul>	on page 1: Changed package to age 1: Changed simplified outli age 1: Changed package to SC page 2: Update 'Marking' sect page 12: Changed package to	ne to SOD882D DD882D ion	
BAP55LX v.3	20110113	Product data sheet	-	BAP55LX v.2
BAP55LX v.2	20101216	Product data sheet	-	BAP55LX v.1
BAP55LX v.1	20070730	Product data sheet	-	-

BAP55LX Product data sheet

### 11. Legal information

### 11.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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